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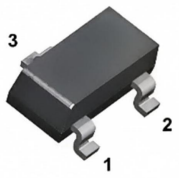
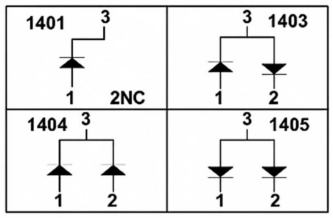
MMBD1401 / MMBD1403 / MMBD1404 / MMBD1405
Small Signal Diodes



SOT-23

Connection Diagrams



Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBD1401	29	SOT-23 3L	Tape and Reel
MMBD1403	32	SOT-23 3L	Tape and Reel
MMBD1404	33	SOT-23 3L	Tape and Reel
MMBD1405	34	SOT-23 3L	Tape and Reel

Absolute Maximum Ratings(1), (2)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter		Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage		200	V
$I_{F(AV)}$	Average Rectified Forward Current		200	mA
I_{FSM}	Non-Repetitive Peak Forward Surge Current	Pulse Width = 1.0 second	1.0	A
		Pulse Width = 1.0 microsecond	2.0	
T_{STG}	Storage Temperature Range		-55 to +150	°C
T_J	Operating Junction Temperature		150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C.
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

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Thermal Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	°C/W

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
B_V	Breakdown Voltage	I_R = 100 μA	200		V
V_F	Forward Voltage	I_F = 10 mA		800	mV
		I_F = 50 mA	760	920	mV
		I_F = 200 mA		1.0	V
		I_F = 300 mA		1.1	V
I_R	Reverse Current	V_R = 120 V		40	nA
		V_R = 175 V		100	nA
C_T	Total Capacitance	V_R = 0, f = 1.0 MHz		2.0	pF
t_{rr}	Reverse Recovery Time	I_F = I_R = 30 mA, I_{RR} = 3.0 mA, R_L = 100 Ω		50	nS

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Typical Performance Characteristics

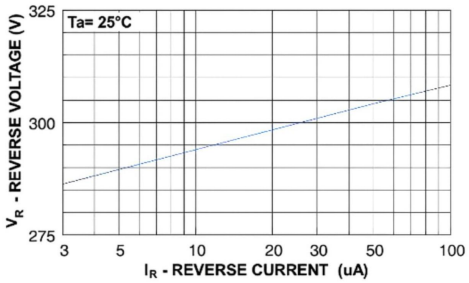

Figure 1. Reverse Voltage vs. Reverse Current
BV - 1.0 to 100 μA

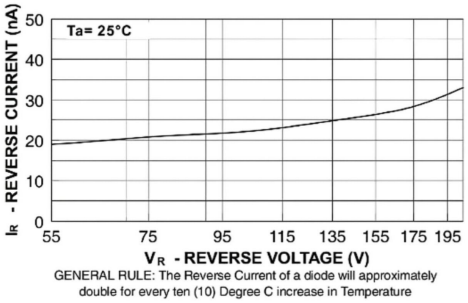

Figure 2. Reverse Current vs. Reverse Voltage
I_R - 55 to 205 V

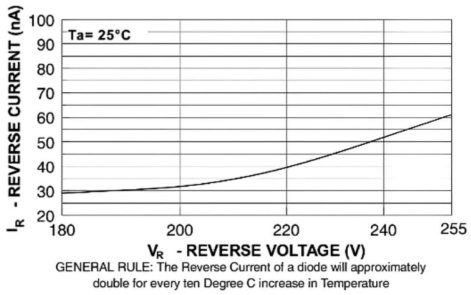

Figure 3. Reverse Current vs. Reverse Voltage
I_R - 180 to 255 V

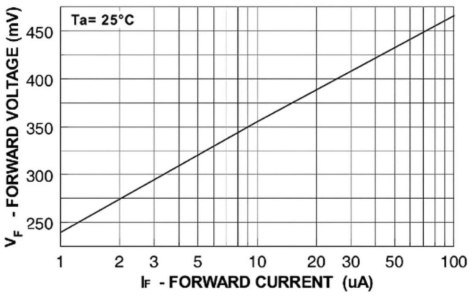

Figure 4. Forward Voltage vs. Forward Current
V_F - 1.0 to 100 μA

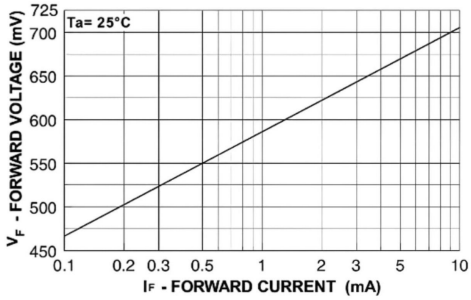

Figure 5. Forward Voltage vs. Forward Current
V_F - 0.1 to 10 mA

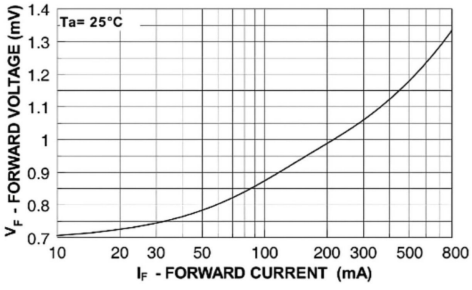

Figure 6. Forward Voltage vs. Forward Current
V_F - 10 to 800 mA

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Typical Performance Characteristics (Continued)

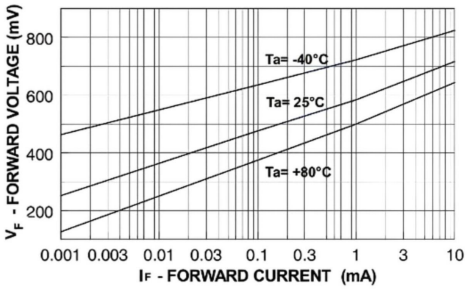

Figure 7. Forward Voltage vs. Ambient Temperature
V_F - 1.0 μA - 10 mA (- 40 to +80°C)

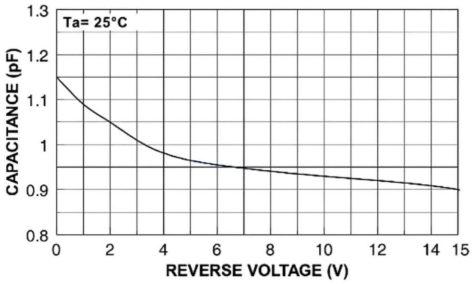

Figure 8. Capacitance vs. Reverse Voltage

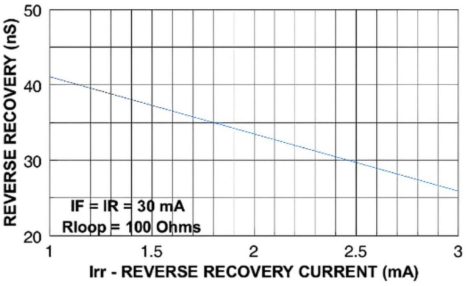

Figure 9. Reverse Recovery Time vs.
Reverse Recovery Current (Irr)

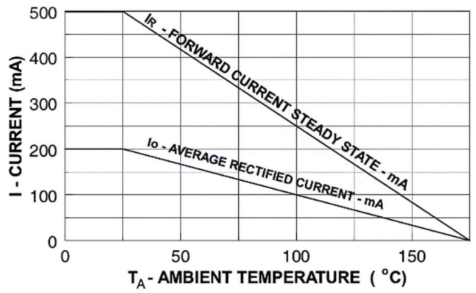

Figure 10. Average Rectified Current(I_O) and
Forward Current (I_F) vs. Ambient Temperature(T_A)

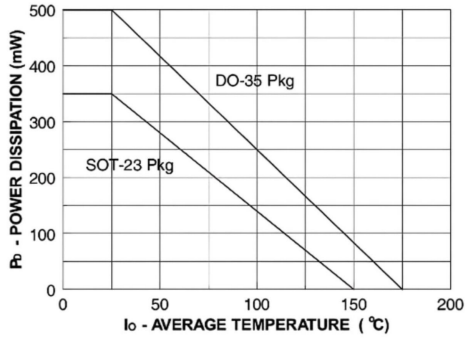

Figure 11. Power Derating Curve

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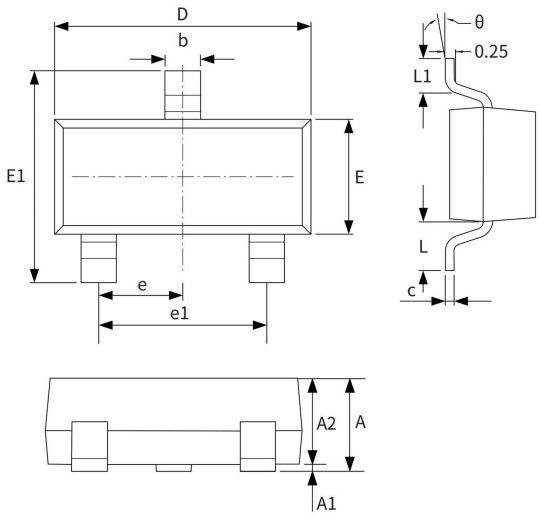
Ordering Information

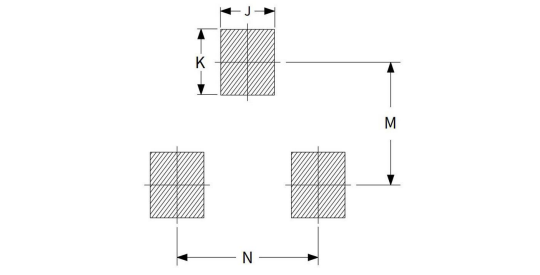
PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-23	R1	0.008	3000	30000	240000	7''

Package Outline Dimensions (SOT-23)



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.15	0.035	0.045
A1	-	0.10	-	0.004
A2	0.90	1.05	0.035	0.041
b	0.30	0.50	0.012	0.020
c	0.10	0.20	0.004	0.008
D	2.80	3.00	0.110	0.118
E	1.20	1.40	0.047	0.055
E1	2.25	2.55	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.80	2.00	0.071	0.079
L	0.550REF		0.022REF	
L1	0.30	0.50	0.012	0.020
θ	-	8°	-	8°

Suggested Pad Layout



Symbol	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
J	0.75	0.85	0.030	0.033
K	0.85	0.95	0.033	0.037
M	1.95	2.05	0.077	0.081
N	1.85	1.95	0.073	0.077